Ordering Information

Part Number	Package	Packing
HV833MG-G	8-Lead MSOP	2500/Reel

⁻G denotes a lead (Pb)-free / RoHS compliant package

Absolute Maximum Ratings

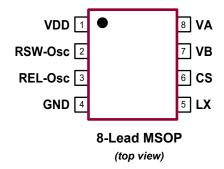
Parameter	Value
Supply voltage V _{DD}	-0.5V to 7.5V
Output voltage, V _{cs}	-0.5V to 125V
Operating temperature	-40°C to +85°C
Storage temperature	-65°C to +150°C
Power dissipation	300mW

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

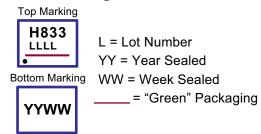
Typical Thermal Resistance

Package	$oldsymbol{ heta}_{ja}$
8-Lead MSOP	216°C/W

Pin Configuration



Product Marking



Package may or may not include the following marks: Si or **9 8-Lead MSOP**

Recommended Operating Conditions

Sym	Parameter	Min	Тур	Max	Units	Conditions
V _{DD}	Supply voltage	1.8	-	6.5	V	
$f_{\scriptscriptstyle{EL}}$	V _{A-B} output drive frequency	60	-	1000	Hz	
T _A	Operating temperature	-25	-	+85	°C	

DC Electrical Characteristics (Over recommended operating conditions unless otherwise specified, $T_A = 25$ °C)

Sym	Parameter	Min	Тур	Max	Units	Conditions
R _{DS(ON)}	On-resistance of switching transistor	-	-	4.0	Ω	I = 100mA
V _{cs}	Max. output regulation voltage	80	90	100	V	V _{DD} = 1.8 to 6.5V
V_{A-B}	Max differential output voltage across lamp	160	180	200	V	$V_{DD} = 1.8 \text{ to } 6.5 \text{V}$
I _{DDQ}	Quiescent V _{DD} supply current	-	-	100	nA	R _{SW-Osc} = Low
I _{DD}	Input current going into the VDD pin	-	-	150	μA	V _{DD} = 1.8 to 6.5V. See Fig. 1
I _{IN}	Input current including inductor current	-	56	64	mA	V _{IN} = 3.3V. See Fig. 1.
V _{cs}	Output voltage on V _{cs}	63	72	81	V	V _{IN} = 3.3V. See Fig. 1.
f _{EL}	V _{DIFF} output drive frequency	240	270	300	Hz	V _{IN} = 3.3V. See Fig. 1.
F _{sw}	Switching transistor frequency	55	65	75	kHz	V _{IN} = 3.3V. See Fig. 1.
D	Switching transistor duty cycle	-	88	-	%	See Fig. 1.

Enable/Disable Function Table

Sym	Parameter	Min	Тур	Max	Units	Conditions
EN-L	Logic input low voltage	0	-	0.5	V	V _{DD} = 1.8 to 6.5V
EN-H	Logic input high voltage	V _{DD} - 0.5	_	V _{DD}	V	V _{DD} = 1.8 to 6.5V

Functional Block Diagram

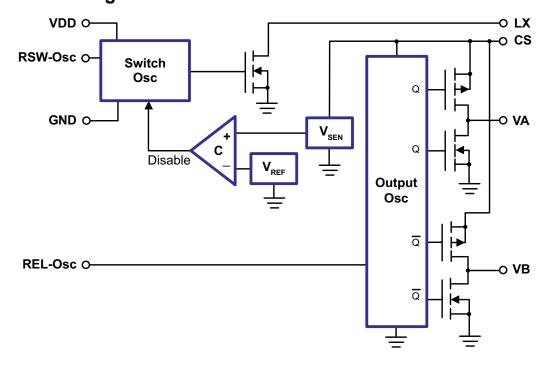
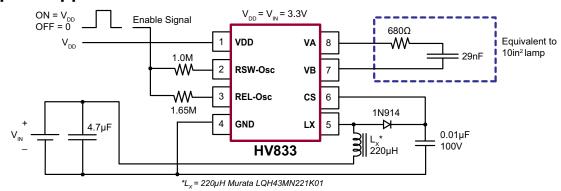


Fig. 1: Typical Application/Test Circuit



Typical Performance

Device	Lamp Size	V _{IN}	I _{IN}	V _{cs}	f _{EL}	Brightness	T _A
HV833MG	10in²	3.3V	56mA	72V	270Hz	5.0ft-lm	-25°C to + 85°C

Typical Performance Curves for Fig. 1 (EL Lamp = 10.0in², $V_{IN} = V_{DD}$)

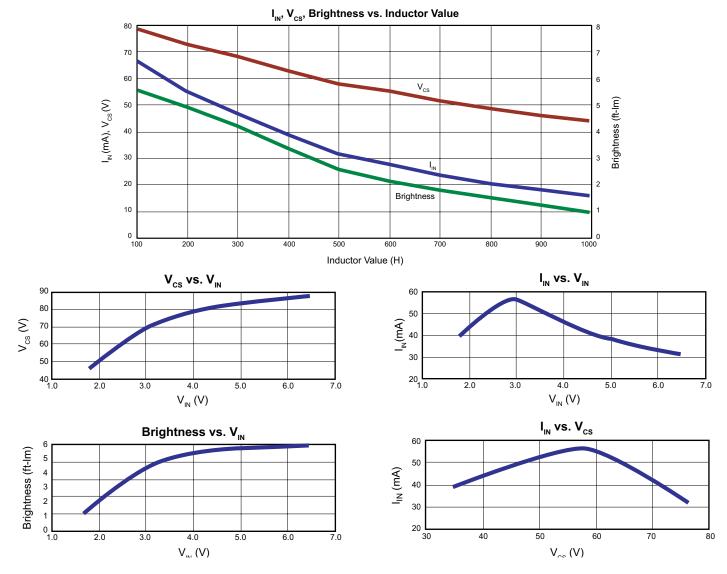
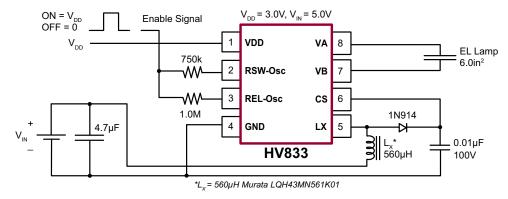


Fig. 2: Typical Application



Typical Performance

Device	Lamp Size	V _{IN}	I _{IN}	V _{cs}	f _{EL}	Brightness	T _A
HV833MG	6.0in ²	5.0V	30mA	70V	440Hz	6.0ft-Im	-25°C to + 85°C

Typical Performance Curves for Fig. 2 (EL Lamp = 6.0in², V_{DD} = 3.0, V_{IN} = 5.0V)

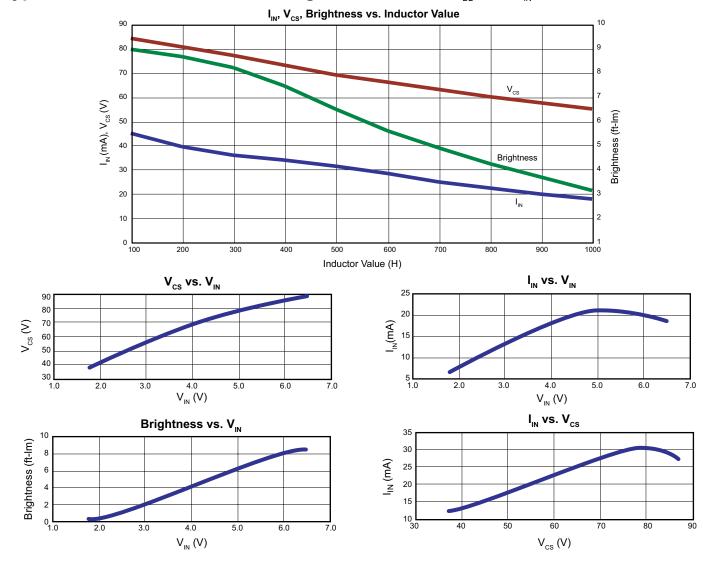
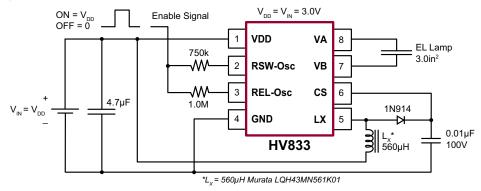


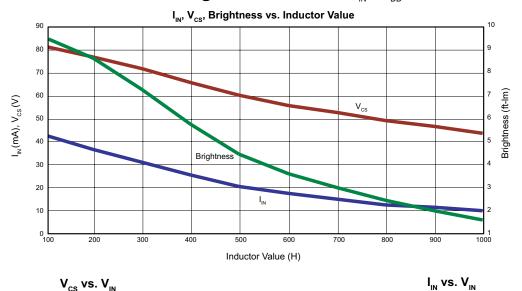
Fig. 3: Typical Application

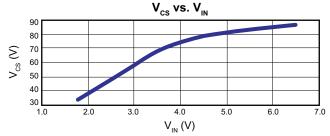


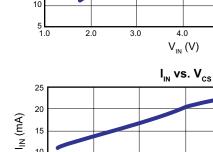
Typical Performance

Device	Lamp Size	V _{IN}	I _{IN}	V _{cs}	f _{EL}	Brightness	T _A
HV833MG	3.0in ²	3.0V	20mA	60V	440Hz	4.0ft-lm	-25°C to + 85°C

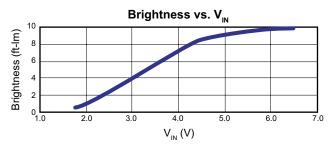
Typical Performance Curves for Fig. 3 (EL Lamp = 3.0in², $V_{IN} = V_{DD}$)

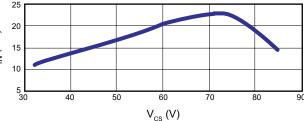






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Enable/Disable Configuration

The HV833 can be easily enabled and disabled via a logic control signal on the R_{SW} and R_{EL} resistors as shown in the Typical Application Circuit on the front page. The control signal can be from a microprocessor. R_{SW} and R_{EL} are typically

very high values. Therefore, only 10's of microamperes will be drawn from the logic signal when it is at a logic high (enable) state. When the microprocessor signal is high the device is enabled and when the signal is low, it is disabled.

Enable/Disable Table

Enable Signal	HV833
V _{DD}	Enable
0V	Disable

Split Supply Configuration for Battery Voltages of Higher than 6.5V

The Typical Application Circuit on the first page can also be used with high battery voltages such as 12V as long as the input voltage, V_{DD}, to the HV833 device is within its specifi-

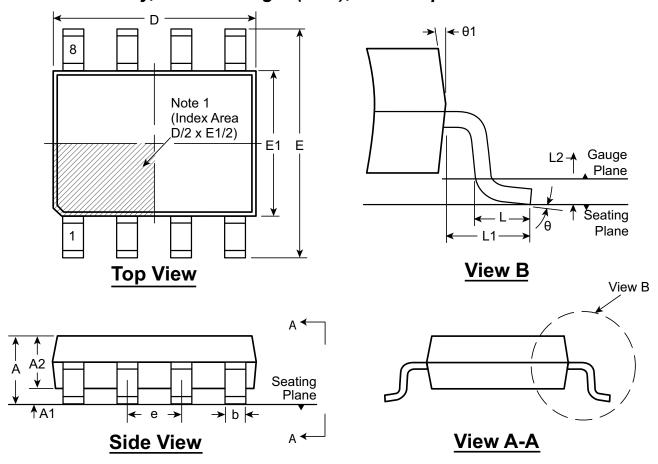
cations of 1.8V to 6.5V. Split supply configuration is shown on Fig. 2.

External Component Description

External Component	Selection Guide Line
Diode	Fast reverse recovery diode, 100V 1N4148 or equivalent.
C _s Capacitor	0.003μF to 0.1μF, 100V capacitor to GND is used to store the energy transferred from the inductor.
R _{EL-Osc}	The EL lamp frequency is controlled via an external R_{EL} resistor connected between REL-Osc and VDD pins of the device. The lamp frequency increases as R_{EL} decreases. As the EL lamp frequency increases, the amount of current drawn from the battery will increase and the output voltage V_{CS} will decrease. The color of the EL lamp is dependent upon its frequency.
R _{sw-Osc}	The switching frequency of the converter is controlled via an external resistor, R_{sw} between the RSW-Osc and VDD pins of the device. The switching frequency increases as R_{sw} decreases. With a given inductor, as the switching frequency increases, the amount of current drawn from the battery will decrease and the output voltage, V_{cs} , will also decrease.
L _x Inductor	The inductor L_x is used to boost the low input voltage by inductive flyback. When the internal switch is on, the inductor is being charged. When the internal switch is off, the charge stored in the inductor will be transferred to the high voltage capacitor C_s . The energy stored in the capacitor is connected to the internal H-bridge, and therefore to the EL lamp. In general, smaller value inductors, which can handle more current, are more suitable to drive larger size lamps. As the inductor value decreases, the switching frequency of the inductor (controlled by R_{sw}) should be increased to avoid saturation. A 220µH Murata (LQH43MN221) inductor with 5.4 Ω series DC resistance is typically recommended. For inductors with the same inductance value but with lower series DC resistance, a lower R_{sw} value is needed to prevent high current draw and inductor saturation.
Lamp	As the EL lamp size increases, more current will be drawn from the battery to maintain high voltage across the EL lamp. The input power, $(V_{IN} \times I_{IN})$, will also increase. If the input power is greater than the power dissipation of the package (300mW), an external resistor in series with one side of the lamp is recommended to help reduce the package power dissipation.

8-Lead MSOP Package Outline (MG)

3.00x3.00mm body, 1.10mm height (max), 0.65mm pitch



Note:

 A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbo	ol	Α	A1	A2	b	D	E	E1	е	L	L1	L2	θ	θ1
	MIN	0.75*	0.00	0.75	0.22	2.80*	4.65*	2.80*		0.40			0 o	5°
Dimension (mm)	NOM	-	-	0.85	-	3.00	4.90	3.00	0.65 BSC	0.60	0.95 REF	0.25 BSC	-	-
()	MAX	1.10	0.15	0.95	0.38	3.20*	5.15*	3.20*	200	0.80			8 º	15°

JEDEC Registration MO-187, Variation AA, Issue E, Dec. 2004.

Drawings are not to scale.

Supertex Doc. #: DSPD-8MSOPMG, Version H041309.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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^{*} This dimension is not specified in the JEDEC drawing.